NSN 5961-00-432-6651

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-432-6651 **Inclosure Material:** Glass **Overall Length:** 0.076 inches **Overall Diameter:** 0.086 inches **Mounting Method:** Terminal **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 50.0 milliwatts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 71.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 ferrule Shelf Life: N/a **Unit Of Measure: Demilitarization:**

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